

# SHANGHAI SUNRISE ELECTRONICS CO., LTD.

## S2AA THRU S2MA

SURFACE MOUNT GLASS PASSIVATED RECTIFIER

TECHNICAL SPECIFICATION

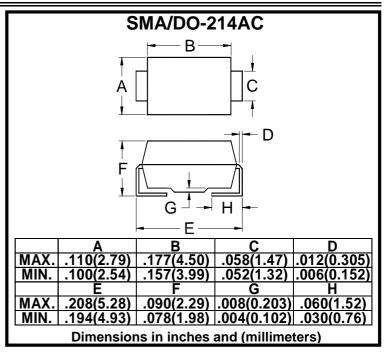
VOLTAGE: 50 TO 1000V CURRENT: 2.0A

#### **FEATURES**

- Ideal for surface mount pick and place application
- Low profile package
- Built-in strain relief
- High surge capability
- High temperature soldering guaranteed: 260°C/10sec/at terminal

#### **MECHANICAL DATA**

- Terminal: Plated leads solderable per MIL-STD 202E, method 208C
- Case: Molded with UL-94 Class V-O recognized flame retardant epoxy
- · Polarity: Color band denotes cathode



### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Single-phase, half-wave,60Hz, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

RATINGS	SYMBOL	S2AA	S2BA	S2DA	S2GA	S2JA	S2KA	S2MA	UNITS
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current (T <sub>L</sub> =110°C)	I <sub>F(AV)</sub>	2.0							Α
Peak Forward Surge Current (8.3ms single half sine-wave superimposed on rated load)	I <sub>FSM</sub>	60							Α
Maximum Instantaneous Forward Voltage (at rated forward current)	$V_{F}$	1.1							V
Maximum DC Reverse Current $T_a=25^{\circ}$ C (at rated DC blocking voltage) $T_a=125^{\circ}$ C	I ID	5.0 200							μA μA
Typical Junction Capacitance (Note 1)	$C_J$	30							pF
Typical Thermal Resistance (Note 2)	$R_{\theta}(ja)$	16							°C/W
Storage and Operation Junction Temperature	$T_{STG},T_{J}$	-65 to +150						°C	

#### Note:

- 1.Measured at 1.0 MHz and applied voltage of 4.0V<sub>dc</sub>
- 2. Thermal resistance from junction to terminal mounted on 5×5mm copper pad area